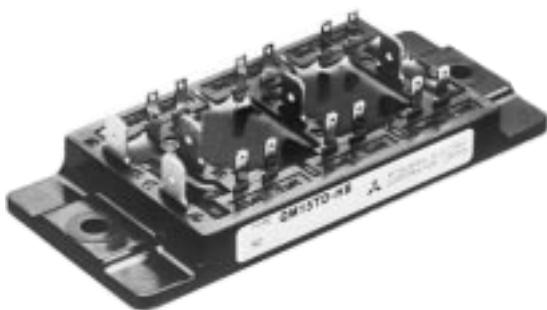


QM15TD-HB



- **I<sub>c</sub>** Collector current ..... **15A**
- **V<sub>CEx</sub>** Collector-emitter voltage ..... **600V**
- **h<sub>FE</sub>** DC current gain ..... **250**
- **Insulated Type**
- **UL Recognized**

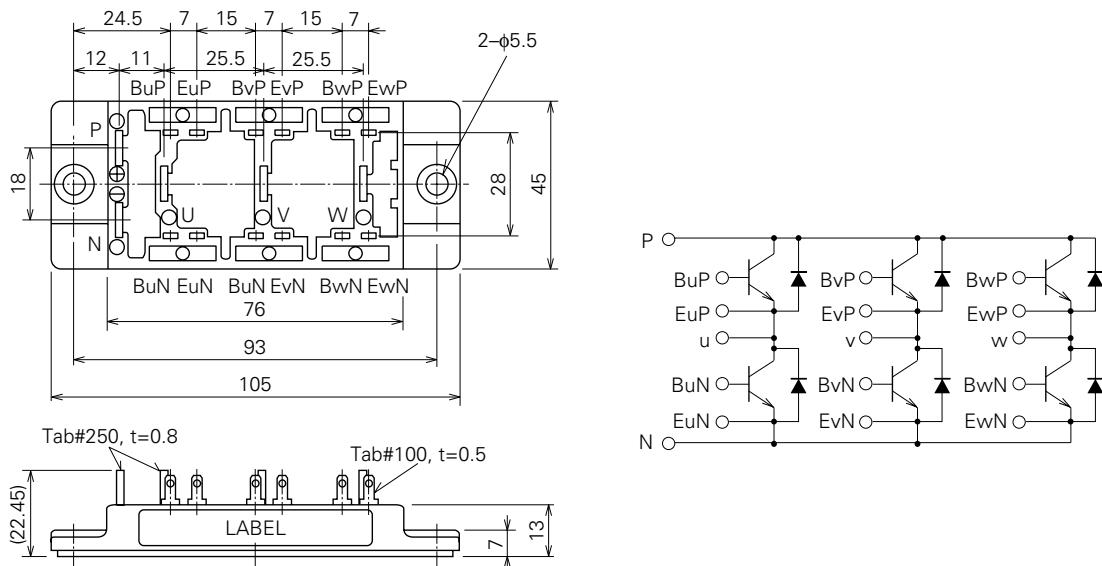
Yellow Card No. E80276 (N)  
File No. E80271

## APPLICATION

Inverters, Servo drives, DC motor controllers, NC equipment, Welders

OUTLINE DRAWING &amp; CIRCUIT DIAGRAM

Dimensions in mm



Note: All Transistor Units are Darlingtons.

**ABSOLUTE MAXIMUM RATINGS** ( $T_j=25^\circ\text{C}$ , unless otherwise noted)

Symbol	Parameter	Conditions	Ratings	Unit
VCE(X SUS)	Collector-emitter voltage	$I_C=1\text{A}$ , $V_{EB}=2\text{V}$	600	V
VCE(X)	Collector-emitter voltage	$V_{EB}=2\text{V}$	600	V
VCBO	Collector-base voltage	Emitter open	600	V
VEBO	Emitter-base voltage	Collector open	7	V
$I_C$	Collector current	DC	15	A
$-I_C$	Collector reverse current	DC (forward diode current)	15	A
Pc	Collector dissipation	$T_c=25^\circ\text{C}$	75	W
$I_B$	Base current	DC	1	A
$-I_{CSM}$	Surge collector reverse current (forward diode current)	Peak value of one cycle of 60Hz (half wave)	150	A
$T_j$	Junction temperature		-40~+150	$^\circ\text{C}$
Tstg	Storage temperature		-40~+125	$^\circ\text{C}$
Viso	Isolation voltage	Charged part to case, AC for 1 minute	2500	V
—	Mounting torque	Mounting screw M5	1.47~1.96	N·m
—			15~20	kg·cm
—	Weight	Typical value	90	g

**ELECTRICAL CHARACTERISTICS** ( $T_j=25^\circ\text{C}$ , unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
ICEX	Collector cutoff current	$V_{CE}=600\text{V}$ , $V_{EB}=2\text{V}$	—	—	1.0	mA
ICBO	Collector cutoff current	$V_{CB}=600\text{V}$ , Emitter open	—	—	1.0	mA
IEBO	Emitter cutoff current	$V_{EB}=7\text{V}$	—	—	40	mA
VCE (sat)	Collector-emitter saturation voltage	$I_C=15\text{A}$ , $I_B=60\text{mA}$	—	—	2.0	V
VBE (sat)	Base-emitter saturation voltage		—	—	2.5	V
$-V_{CEO}$	Collector-emitter reverse voltage	$-I_C=15\text{A}$ (diode forward voltage)	—	—	1.5	V
$hFE$	DC current gain	$I_C=15\text{A}$ , $V_{CE}=2\text{V}$	250	—	—	—
$t_{on}$	Switching time	$V_{CC}=300\text{V}$ , $I_C=15\text{A}$ , $I_B1=90\text{mA}$ , $I_B2=-300\text{mA}$	—	—	1.5	$\mu\text{s}$
$t_s$			—	—	10	$\mu\text{s}$
$t_f$			—	—	2.0	$\mu\text{s}$
$R_{th(j-c) Q}$	Thermal resistance (junction to case)	Transistor part (per 1/6 module)	—	—	1.65	$^\circ\text{C}/\text{W}$
$R_{th(j-c) R}$		Diode part (per 1/6 module)	—	—	2.8	$^\circ\text{C}/\text{W}$
$R_{th(c-f)}$	Contact thermal resistance (case to fin)	Conductive grease applied (per 1/6 module)	—	—	0.35	$^\circ\text{C}/\text{W}$